

Low Power, High Voltage SPST Analog Switches

DESCRIPTION

The DG447, DG448 are dual supply single-pole/single-throw (SPST) switches. On resistance is 25 W maximum and flatness is 2.2 W max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG477, DG448 are also ideally suited for portable and battery powered industrial and military equipment.

The DG477 has one normally closed switch, while the DG448 switch is normally open. They operate either from a single + 7 V to 36 V supply or from dual \pm 4.5 V to \pm 20 V supplies. They are offered in the very popular, small TSOP6 package.

FEATURES

- ± 15 V analog signal range
- On-resistance $R_{DS(on)}$: 25 Ω max.
- Fast switching action t_{ON}: 100 ns
- V_I logic supply not required
- TTL CMOS input compatible
- Rail to rail signal handling
- Dual or single supply operation
- Compliant to RoHS Directive 2002/95/EC

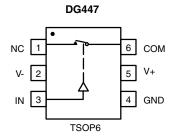
BENEFITS

- Wide dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability

APPLICATIONS

- · Precision test equipment
- Precision instrumentation
- Communications systems
- PBX. PABX systems
- Audio equipment
- Redundant systems
- PC multimedia boards
- Hard disc drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



_				
	• \		_	
NO 1	را ب		6	COM
V- 2	ļ	F	5	V+
IN 3		F	4	GND
L	TSOP6			

DG448

TRUTH TABLE							
Logic	DG447	DG448					
0	ON	OFF					
1	OFF	ON					

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

Device Marking: DG447DV = G5xxxDG448DV = G6xxx





ORDERING INFORMATION						
Temp. Range	Package	Part Number				
DG447, DG448						
- 40 °C to 85 °C	6-pin TSOP	DG447DV-T1-E3				
- 40 0 10 65 0	0-piii 130F	DG448DV-T1-E3				

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
Parameter Referenced to V-		Limit	Unit		
V+		44			
GND		25	V		
Digital Inputs ^a , V _{no/nc} , V _{COM}		(V-) - 2 V to (V+) + 2 V or 30 mA, whichever occurs first	•		
Current , (Any Terminal) Continuous		30	mA		
Current (NO or NC or COM) Pulsed at 1 ms, 10 % Duty Cycle		100	IIIA		
Storage Temperature		- 65 to 150	°C		
Power Dissipation (Package) ^b	6-pin TSOP ^c	570	mW		

- Notes:
 a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
 b. All leads welded or soldered to PC board.
 c. Derate 7 mW/°C above 70 °C.

		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V		D Suffix - 40 °C to 85 °C			
Parameter	Symbol	$V_{1N} = 13 \text{ V}, V_{1} = 13 \text{ V}$ $V_{1N} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp.b	Min. ^d	Typ. ^c	Max. ^d	Unit
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	- 15		15	V
Drain-Source On-Resistance	R _{ON}	I _{no/nc} = 10 mA, V _{COM} = 10 V V+ = 13.5 V, V- = - 13.5 V	Room Full		17	25 30	Ω
On-Resistance Flatness	R _{ON} Flatness	$I_{\text{no/nc}} = 10 \text{ mA}, V_{\text{COM}} = \pm 5 \text{ V}, 0 \text{ V}$ V+ = 13.5 V, V- = - 13.5 V	Room Full		0.8	2.2 3	32
Switch Off Leakage Current	I _{no/nc(off)}	V+ = 16.5, V- = - 16.5 V V _{COM} = ± 15.5 V	Room Full	- 1 - 10	- 0.1	1 10	
Switch Oil Leakage Current	I _{COM(off)}	$V_{\text{no/nc}} = -/+ 15.5 \text{ V}$	Room Full	- 1 - 10	- 0.1	1 10	nA
Channel On Leakage Current	I _{COM(on)}	V+ = 16.5 V, V- = -16.5 $V_{COM} = V_{no/nc} = \pm 15.5 \text{ V}$	Room Full	- 1 - 10	- 0.1	1 10	
Digital Control							
Input, High Voltage	I _{INH}		Full	2.4			V
Input, Low Voltage	I _{INL}		Full			0.8	V
Input Capacitance ^e	C _{IN}		Room		5		pF
Input Current	I _{IN}	V _{IN} = 0 or 5 V		- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t _{ON}	D 000 0 0 05 #F	Room Full		100	130 140	no
Turn-Off Time	t _{OFF}	$R_L = 300 \Omega, C_L = 35 pF$ $V_{no/nc} = \pm 10 V$	Room Full		50	95 110	ns
Charge Injection ^e	Q	$C_L = 10 \text{ nF, } V_{gen} = 0 \text{ V, } R_{gen} = 0 \Omega$	Room		10		рС
Off-Isolation ^e	OIRR	$C_L = 5 \text{ pF}, R_L = 50 \Omega, f = 1 \text{ MHz}$	Room		- 72		dB
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room		19		
Drain Off Capacitance ^e	C _{D(off)}	1 – 1 1011 12	Room		8		pF
Channel On Capacitance ^e	C _{D(on)}	f = 1 MHz	Room		30		
Power Supplies							
Positive Supply Current	l+	V+ = 16.5 V, V- = - 16.5 V	Room Full		16	30 50	μА
Negative Supply Current	I-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full	- 1 - 10	- 0.02		μΑ

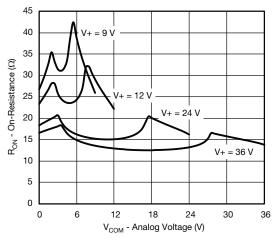


SPECIFICATIONS ^a								
		Test Conditions Unless Otherwise Specified V+ = 12 V, V- = 0 V		D Suffix - 40 °C to 85 °C		°C	°C	
Parameter	Symbol	$V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{f}$	Temp.b	Min. ^d	Typ.c	Max. ^d	Unit	
Analog Switch								
Analog Signal Range ^e	V _{ANALOG}		Full	0		12	V	
Drain-Source On-Resistance	R _{ON}	$I_{\text{no/nc}} = -10 \text{ mA}, V_{\text{COM}} = 8 \text{ V}$ V+ = 10.8 V	Room Full		32	45 60	Ω	
On-Resistance Flatness	R _{ON} Flatness	I _{no/nc} = 10 mA, V _{COM} = 2, 6, 8 V V+ = 10.8 V	Room Full		2	6 8	Ω	
Dynamic Characteristics	_							
Turn-On Time	t _{ON}	$V_{NO, NC} = \pm 10 \text{ V}, R_L = 300 \Omega, C_L = 35 \text{ pF}$	Room Full		140	175 225	nS	
Turn-Off Time	t _{OFF}	NO, NC - ± 10 v, 11 = 500 s2, 5 = 55 pi	Room Full		50	120 150	113	
Charge Injection ^e	Q	$C_L = 10 \text{ nF}, V_{gen} = 0 \text{ V}, R_{gen} = 0 \Omega$	Room		12		рC	
Power Supplies							•	
Positive Supply Current	I+	V+ = 13.2 V, V _{IN} = 0 V, 5 V	Room Full		22	50 75	μΑ	

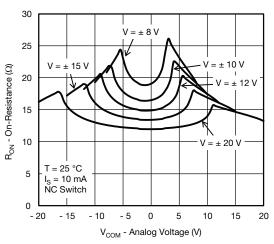
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

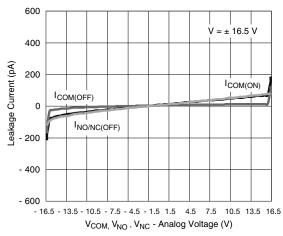
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



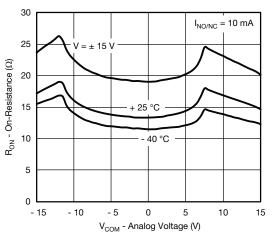
 $\rm R_{ON}$ vs. $\rm V_{COM}$ and Single Supply Voltage



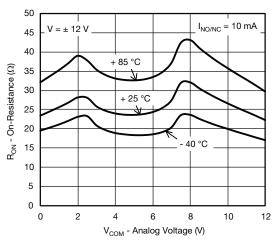
 R_{ON} vs. V_{COM} and Dual Supply Voltage



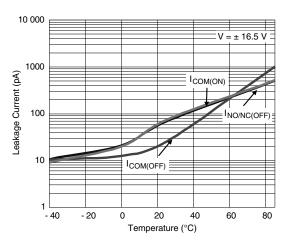
Leakage vs. Analog Voltage



R_{ON} vs. Analog Voltage and Temperature



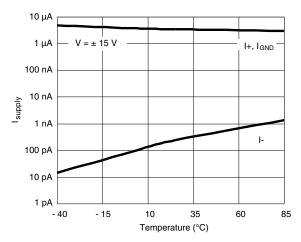
 $\ensuremath{\text{R}_{\text{ON}}}$ vs. Analog Voltage and Temperature



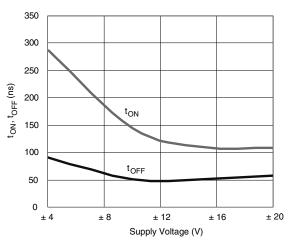
Leakage Current vs. Temperature



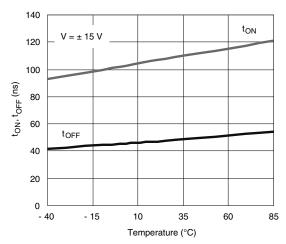
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



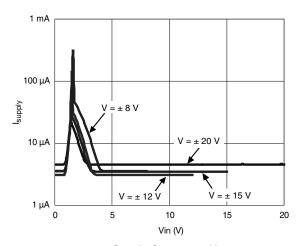
Supply Current vs. Temperature



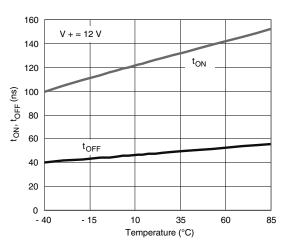
Switching Time vs. Supply Voltages



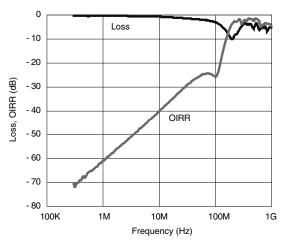
Switching Time vs. Temperature



Supply Current vs. V_{IN}

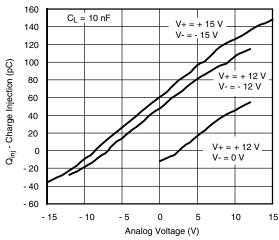


Switching Time vs. Temperature

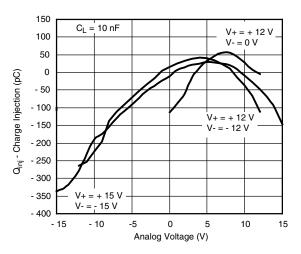


Off Isolation and Insertion Loss vs. Frequency

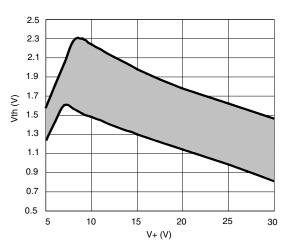
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage (Measured at COM pin)



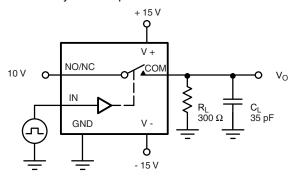
Charge Injection vs. Analog Voltage (Measured at NC or NO pin)



Input Switching Threshold vs. Supply Voltage

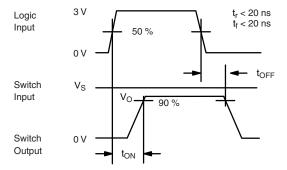
TEST CIRCUITS

V_O is the steady state output with the switch on.



C_L (includes fixture and stray capacitance)

$$V_O = V_S$$
 $\frac{R_L}{R_L + r_{ON}}$



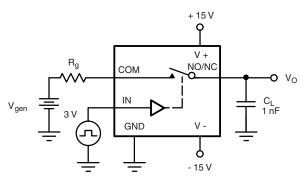
Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



TEST CIRCUITS

V_O is the steady state output with the switch on.



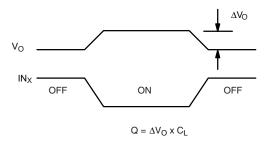
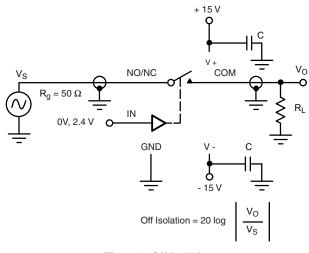


Figure 2. Charge Injection



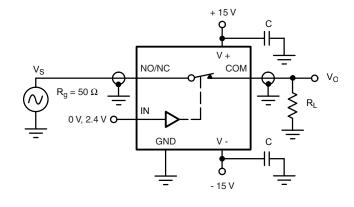


Figure 3. Off Isolation

Figure 4. Insertion Loss

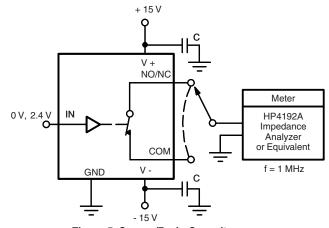


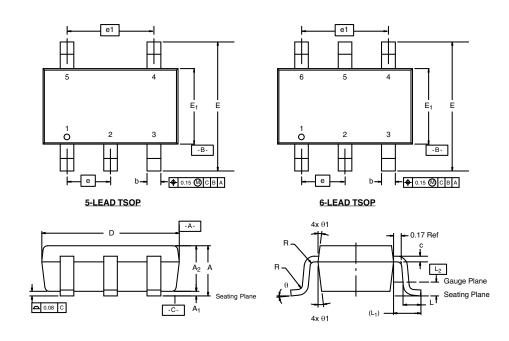
Figure 5. Source/Drain Capacitances

Vishay General Semiconductor



TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C



DIM.		MILLIMETERS INCHES						
DIWI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.91	-	1.10	0.036	-	0.043		
A ₁	0.01	-	0.10	0.0004	-	0.004		
A ₂	0.90	-	1.00	0.035	0.038	0.039		
b	0.30	0.32	0.45	0.012	0.013	0.018		
С	0.10	0.15	0.20	0.004	0.006	0.008		
D	2.95	3.05	3.10	0.116	0.120	0.122		
Е	2.70	2.85	2.98	0.106	0.112	0.117		
E ₁	1.55	1.65	1.70	0.061	0.065	0.067		
е		0.95 BSC			0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.075	0.079		
L	0.32	-	0.50	0.012	-	0.020		
L ₁		0.60 Ref.			0.024 Ref.			
L ₂		0.25 BSC		0.010 BSC				
R	0.10	-	-	0.004	-	-		
θ	0°	4°	8°	0°	4°	8°		
θ_1		7° Nom.		7° Nom.				

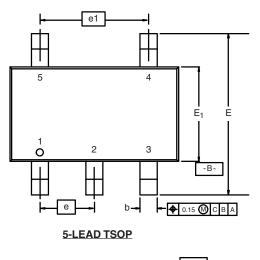
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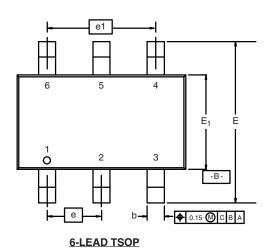




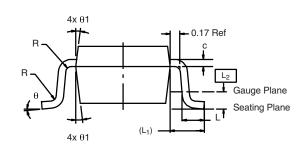
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C





-A-D · A_2 Seating Plane **a** 0.08 C -C- A₁

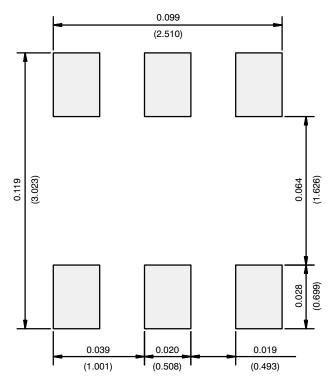


	MIL	LIMETER	RS	ı	NCHES			
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.91	-	1.10	0.036	-	0.043		
A ₁	0.01	-	0.10	0.0004	-	0.004		
A ₂	0.90	-	1.00	0.035	0.038	0.039		
b	0.30	0.32	0.45	0.012	0.013	0.018		
С	0.10	0.15	0.20	0.004	0.006	0.008		
D	2.95	3.05	3.10	0.116	0.120	0.122		
Е	2.70	2.85	2.98	0.106	0.112	0.117		
E ₁	1.55	1.65	1.70	0.061	0.065	0.067		
е		0.95 BSC			0.0374 BSC	;		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079		
L	0.32	-	0.50	0.012	-	0.020		
L ₁		0.60 Ref			0.024 Ref			
L ₂		0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-		
θ	0°	4°	8°	0°	4°	8°		
θ_1		7° Nom		7° Nom				
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540								

Document Number: 71200 www.vishay.com 18-Dec-06

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)

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